

M.Sc.(Physics) CBCS Pattern Semester-I
PSCPHYT03 - Core Paper-III : Electronics

P. Pages : 2

Time : Three Hours



GUG/W/23/11181

Max. Marks : 80

Either:

1. a) Explain construction and working of n-channel JFET. 8
- b) Explain construction and working of SCR. Discuss the characteristics of a silicon controlled rectifier with the help of a circuit diagram. 8

OR

- e) Explain construction and working of n-channel enhancement MOSFET. 8
- f) Discuss in details Schottky and Tunnel diodes. 8

Either:

2. a) Explain construction and working of RC coupled amplifier. 8
- b) What is oscillator? Draw circuit diagram of Hartley oscillator and obtain an expression for frequency of oscillator. 8

OR

- e) Draw circuit diagram of clipping and clamping and explain its working. 8
- f) Explain working of JFET as an amplifier. 8

Either:

3. a) Explain working of OPAMP as a differentiator and integrator. 8
- b) Explain Half and Full adder with diagram and its truth table. 8

OR

- e) Explain working of operational amplifier as comparator and Schmitt trigger generator. 8
- f) Explain construction and working of sweep generator using SCR. 8

Either:

- 4. a) Explain working of amplitude modulation & demodulation. 8
- b) Discuss microwave oscillators in details. 8

OR

- e) Explain working of cavity resonators in details. 8
 - f) Explain digital (PCM) modulation in details. 8
5. Attempt all of the followings.
- a) Explain construction and working of photo transistor. 4
 - b) Construct OR and AND gate using transistor. 4
 - c) Discuss operational Amplifier as a inverting amplifier. 4
 - d) Why modulation necessary in communication? Define frequency modulation. 4
